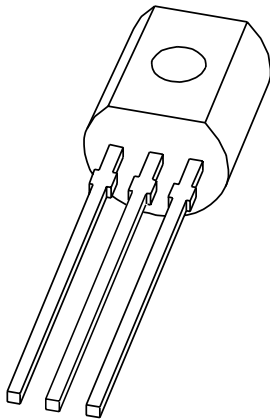


# DATA SHEET



**2PC1815**

**NPN general purpose transistor**

Product specification  
Supersedes data of 1999 May 28

2004 Nov 05

NPN general purpose transistor

2PC1815

FEATURES

- Low current (max. 150 mA)
- Low voltage (max. 50 V).

APPLICATIONS

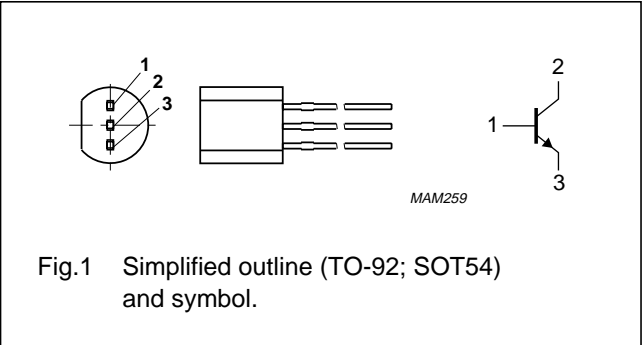
- General purpose switching and amplification, e.g. audio amplifier driver stages.

DESCRIPTION

NPN transistor in a TO-92 (SOT54) plastic package.  
PNP complement: 2PA1015.

PINNING

PIN	DESCRIPTION
1	base
2	collector
3	emitter



ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
2PC1815	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	60	V
$V_{CEO}$	collector-emitter voltage	open base	–	50	V
$V_{EBO}$	emitter-base voltage	open collector	–	5	V
$I_C$	collector current (DC)		–	150	mA
$I_{CM}$	peak collector current		–	200	mA
$I_{BM}$	peak base current		–	200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ }^{\circ}\text{C}$ ; note 1	–	500	mW
$T_{stg}$	storage temperature		–65	+150	$^{\circ}\text{C}$
$T_j$	junction temperature		–	150	$^{\circ}\text{C}$
$T_{amb}$	ambient temperature		–65	+150	$^{\circ}\text{C}$

Note

1. Transistor mounted on an FR4 printed-circuit board.

## NPN general purpose transistor

## 2PC1815

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th(j-a)}$	thermal resistance from junction to ambient	note 1	250	K/W

## Note

1. Transistor mounted on an FR4 printed-circuit board.

## CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 60\text{ V}; I_E = 0\text{ A}$	–	–	100	nA
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 5\text{ V}; I_C = 0\text{ A}$	–	–	100	nA
$h_{FE}$	DC current gain	$V_{CE} = 6\text{ V}; I_C = 150\text{ mA}$	25	–	–	
$h_{FE}$	DC current gain	$V_{CE} = 6\text{ V}; I_C = 2\text{ mA}$				
	2PC1815		120	–	700	
	2PC1815Y		120	–	240	
	2PC1815GR		200	–	400	
	2PC1815BL		350	–	700	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 100\text{ mA}; I_B = 10\text{ mA}$	–	–	300	mV
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 100\text{ mA}; I_B = 10\text{ mA}$	–	–	1.1	V
$C_c$	collector capacitance	$V_{CB} = 10\text{ V}; I_E = I_C = 0\text{ A};$ $f = 1\text{ MHz}$	–	2.5	3.5	pF
$f_T$	transition frequency	$V_{CE} = 6\text{ V}; I_C = 1\text{ mA}; f = 100\text{ MHz}$	80	–	–	MHz
F	noise figure	$V_{CE} = 5\text{ V}; I_C = 200\text{ }\mu\text{A};$ $R_S = 2\text{ k}\Omega; f = 1\text{ kHz}$	–	–	10	dB

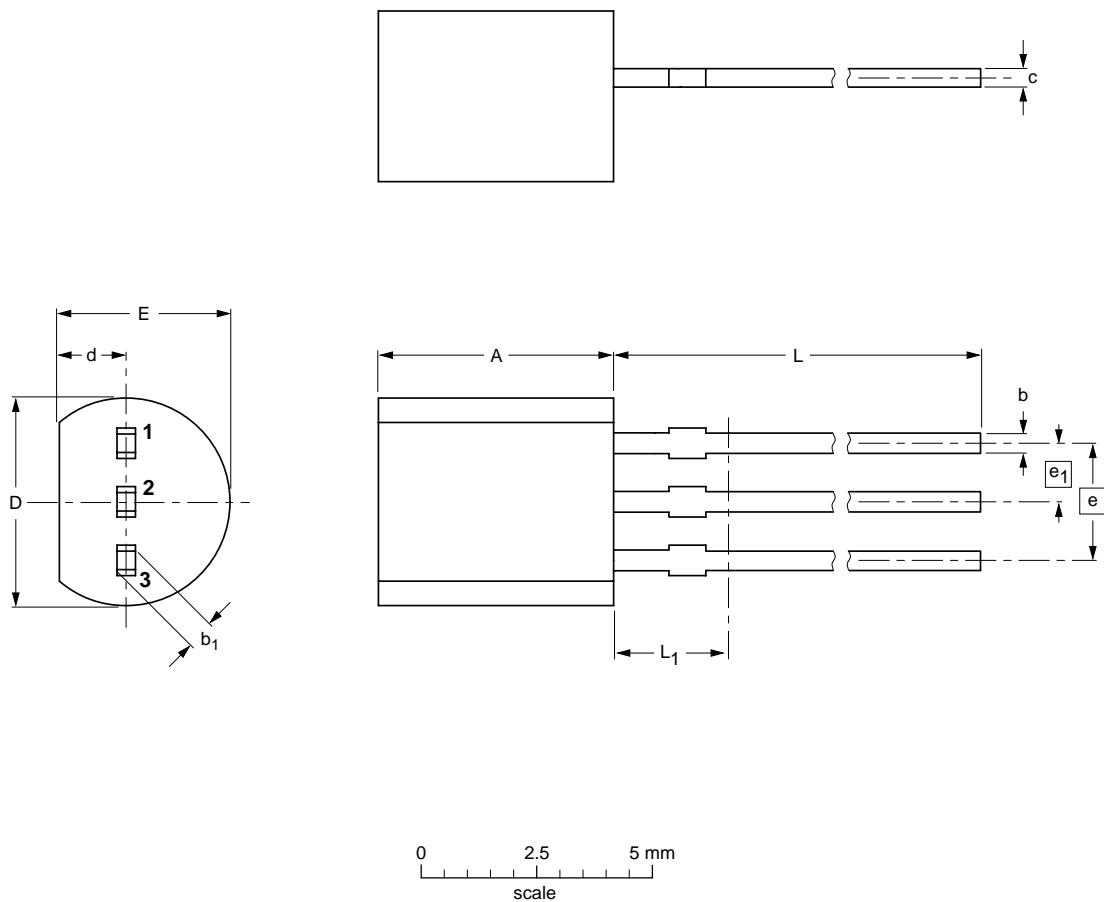
NPN general purpose transistor

2PC1815

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54




DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b <sub>1</sub>	c	D	d	E	e	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup> max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT54		TO-92	SC-43A			-97-02-28 04-06-28

## NPN general purpose transistor

2PC1815

## DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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